1 General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

PNP complements: BCW68F/G/H

2 Features and benefits

High current

AEC-Q101 qualified

3 Applications

· General-purpose switching and amplification

4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base		-	-	45	V
I _C	collector current			-	-	800	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	1	Α
h _{FE}	DC current gain	V_{CE} = 1 V; I_{C} = 100 mA; T_{amb} = 25 °C	[1]				
	BCW66F			100	-	250	
	BCW66G			160	-	400	
	BCW66H			250	-	600	

[1] pulsed: $t_p \le 300 \mu s$, $\delta \le 0.02$



5 Pinning information

Table 2. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base		
2	Е	emitter	3	C
3	С	collector		BE sym123

6 Ordering information

Table 3. Ordering information

	Table of Grading Information						
Type number	Package						
	Name	Description	Version				
BCW66F	TO-236AB	plastic surface-mounted package; 3 leads	SOT23				
BCW66G							
BCW66H							

7 Marking

Table 4. Marking

Table 4. Marking					
Type number		Marking code			
BCW66F	[1]	EQ%			
BCW66G	[1]	ER%			
BCW66H	[1]	ES%			

^{[1] % =} placeholder for manufacturing site code

8 Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	50	V
V_{CEO}	collector-emitter voltage	open base	-	45	V
V_{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current		-	800	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	1	Α
I _B	base current		-	100	mA

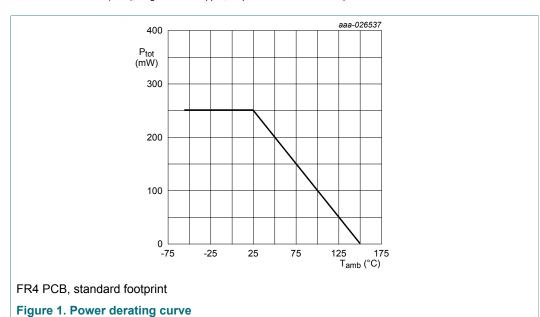
BCW66x_SER

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Symbol	Parameter	Conditions	Min	Max	Unit
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms	-	200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$ [1]	-	250	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	150	°C
T _{stg}	storage temperature		-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB), single-sided chopper, tin-plated and standard footprint.

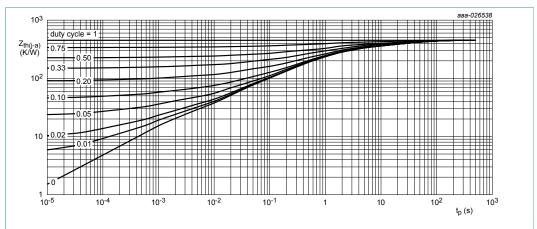


9 Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air [1]	-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



FR4 PCB, standard footprint

Figure 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10 Electrical characteristics

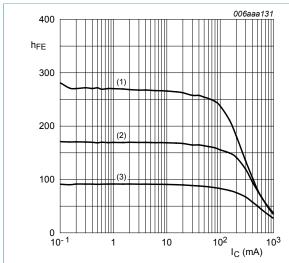
Table 7. Electrical characteristics

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base	V _{CB} = 40 V; I _E = 0 A		-	-	20	nA
	cut-off current	V _{CB} = 40 V; I _E = 0 A; T _j = 150 °C		-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A		-	-	20	nA
h _{FE}	DC current gain						
	BCW66F/G/H	V _{CE} = 1 V; I _C = 100 μA		75	-	-	
	BCW66F/G/H	V _{CE} = 1 V; I _C = 1 mA		75	-	-	
	BCW66F/G/H	V _{CE} = 1 V; I _C = 10 mA		75	-	-	
	BCW66F	V _{CE} = 1 V; I _C = 100 mA	[1]	100	-	250	
	BCW66G		[1]	160	-	400	
	BCW66H		[1]	250	-	630	
	BCW66F/G/H	V _{CE} = 1 V; I _C = 500 mA	[1]	40	-	-	
V _{CEsat}	collector-emitter	I _C = 100 mA; I _B = 10 mA	[1]	-	-	350	mV
	saturation voltage	I _C = 500 mA; I _B = 50 mA	[1]	-	-	450	mV
V _{BEsat}	base-emitter	I _C = 100 mA; I _B = 10 mA	[1]	-	-	1.25	V
	saturation voltage	I _C = 500 mA; I _B = 50 mA	[1]	-	-	1.25	V
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz		100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = I_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	3	-	pF

^[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$

Table 8.



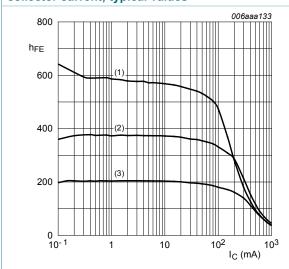
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Figure 3. BCW66F: DC current gain as a function of collector current; typical values



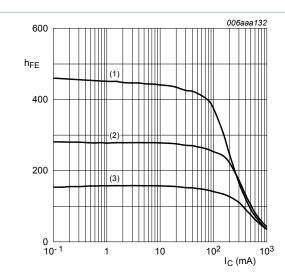
$$V_{CE} = 1 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = -55 °C$$

Figure 5. BCW66H: DC current gain as a function of collector current; typical values

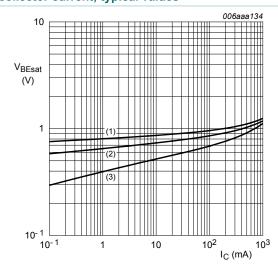


$$V_{CE} = 1 V$$

(2)
$$_{amb}$$
 = 25 $^{\circ}$ C

(3)
$$_{amb}$$
 = -55 $^{\circ}$ C

Figure 4. BCW66G: DC current gain as a function of collector current; typical values

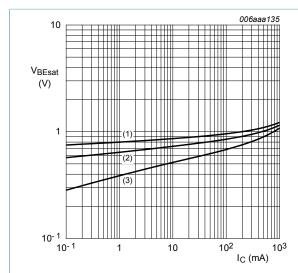


$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55$$
 °C

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Figure 6. BCW66F: Base-emitter saturation voltage as a function of collector current; typical values

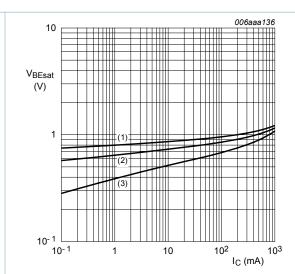


$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$



$$I_{\rm C}/I_{\rm B} = 10$$

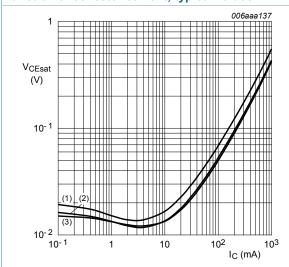
(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Figure 7. BCW66G: Base-emitter saturation voltage as a function of collector current; typical values

Figure 8. BCW66H: Base-emitter saturation voltage as a function of collector current; typical values



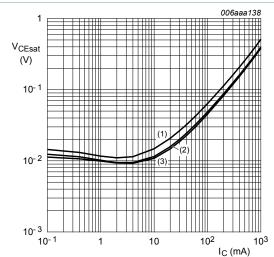
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Figure 9. BCW66F: Collector-emitter saturation voltage as a function of collector current; typical values



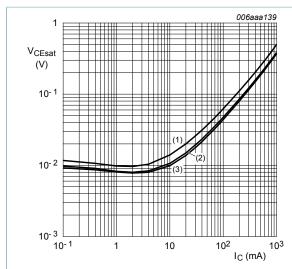
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Figure 10. BCW66G: Collector-emitter saturation voltage as a function of collector current; typical values



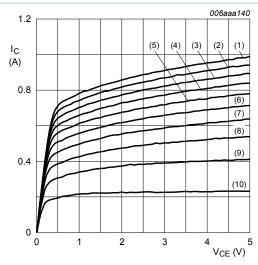
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb}$$
 = 150 °C

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb}$$
 = -55 °C

Figure 11. BCW66H: Collector-emitter saturation voltage as a function of collector current; typical values



 T_{amb} = 25 °C

(1) $I_B = 16.0 \text{ mA}$

(2) $I_B = 14.4 \text{ mA}$

(3) $I_B = 12.8 \text{ mA}$

(4) $I_B = 11.2 \text{ mA}$

(5) $I_B = 9.6 \text{ mA}$ (6) $I_B = 8.0 \text{ mA}$

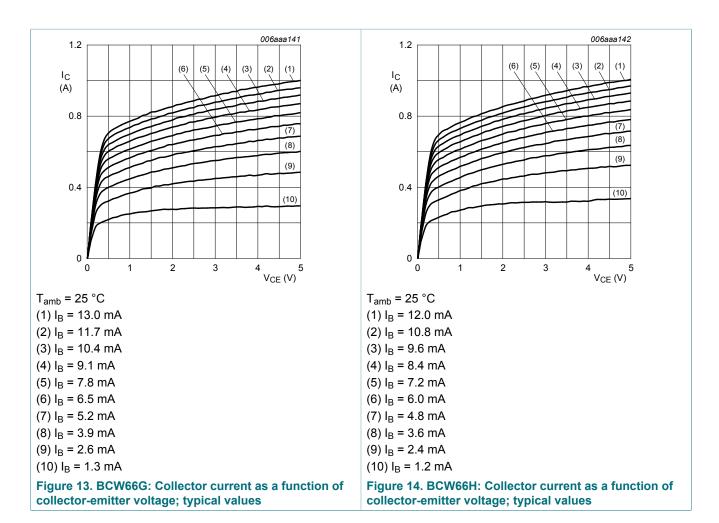
 $(7) I_B = 6.4 \text{ mA}$

(8) $I_B = 4.8 \text{ mA}$

(9) $I_B = 3.2 \text{ mA}$

 $(10) I_B = 1.6 mA$

Figure 12. BCW66F: Collector current as a function of collector-emitter voltage; typical values



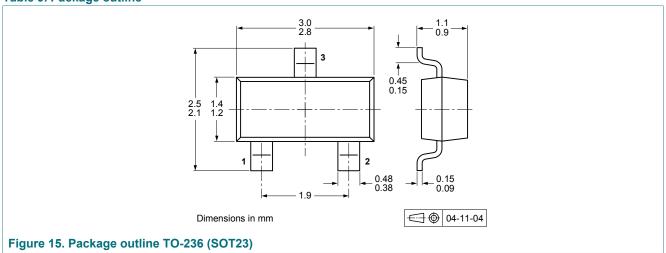
11 Test information

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This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

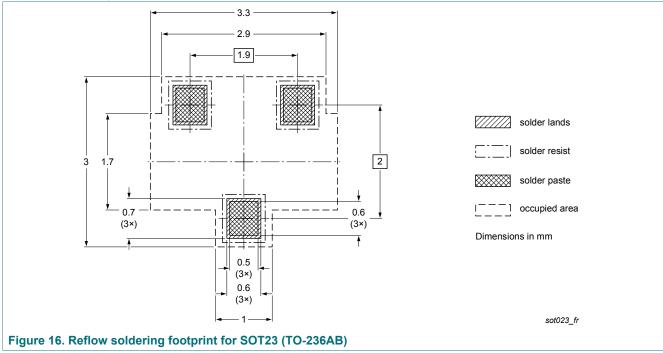
12 Package outline

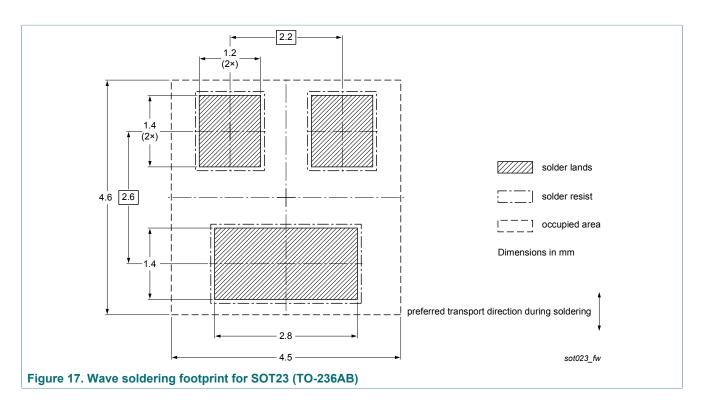
Table 9. Package outline



13 Soldering

Table 10. Soldering





14 Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BCW66x_SER v.1	21 April 2017	Product data sheet	-	-

15 Legal information

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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BCW66 series

45 V, 800 mA NPN general-purpose transistor

(TO-236AB)10

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BCW66 series

45 V, 800 mA NPN general-purpose transistor

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